What does APV means?

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Abstract

This paper presents the results of researches of the effects of abnormally high photovoltaic voltage (APV) in the semiconductor film systems. The possibility of using of open channel optical couples for optoelectronic systems based on transmitter and APV-receiver was investigated. On the basis of APV-films new systems for various optoelectronic has been developed.

Key words

APV-films, optoelectronics, scientific information.

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